

IRS21867STRPBF

Data Sheet

Power Driver ICs Hi CUR Iout = 4A robust HS/LS Gt Drvr

Manufacturers	Infineon Technologies Corporation	
Package/Case	SOIC-8	
Product Type	Power Management ICs	
RoHS		
Lifecycle		Images are for reference only

Please submit RFQ for IRS21867STRPBF or Email to us: sales@ovaga.com We will contact you in 12 hours.

General Description

600 V high and low-side gate driver IC for IGBTs and MOSFETs with typical 4 A source and 4 A sink currents in 8 Lead SOIC package.

Features

Floating channel designed for bootstrap operation

Fully operational to +600 V

Tolerant to negative transient voltage, dV/dt immune

Low VCC operation

Gate drive supply range from 5 V to 20 V

Undervoltage lockout for both channels

3.3 V and 5 V input logic compatible

Matched propagation delay for both channels

Logic and power ground +/- 5 V offset

Lower di/dt gate driver for better noise immunity

Output source/sink current capability 4.0 A (Typ.)

Application

Home appliances Refrigerators Induction cooking Motor control and drives Robotics Home and building automation Industrial heating and welding Power tools Power supplies Uninterruptible power supply (UPS)

Multicopters and drones





Related Products



IRS2101SPBF

Infineon Technologies Corporation SOIC-8



IRS21864SPBF

Infineon Technologies Corporation SOIC-14



IRS2003STRPBF

Infineon Technologies Corporation SOIC-8

IR3897MTRPBF

Infineon Technologies Corporation PQFN 4 x 5 $\,$



IR3898MTRPBF

Infineon Technologies Corporation PQFN 4 x 5



IR21531SPBF

Infineon Technologies Corporation SOIC-8



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Infineon Technologies Corporation SOIC-8



IR1168SPBF

Infineon Technologies Corporation SOIC-8